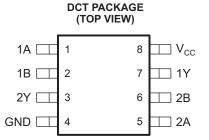


## FEATURES

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V •
- Max t<sub>pd</sub> of 3.8 ns at 3.3 V •
- Low Power Consumption, 10-µA Max Icc •
- ±24-mA Output Drive at 3.3 V ٠
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC}^{-1}$  = 3.3 V, T<sub>A</sub> = 25°C

- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C
- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



	(TOP VIEW)											
1A 📺	1	8	□ V <sub>cc</sub>									
1B 🗔	2	7	∐ 1Y									
2Y 🗔	3	6	<u> </u>									
GND 🖂	4	5	□ 2A									

YZP PACKAGE (BOTTOM VIEW)										
GND	O4 50	2A								
2Y	O36O	2B								
1B	0270	1Y								
1A	0180	$V_{CC}$								

See mechanical drawings for dimensions.

## **DESCRIPTION/ORDERING INFORMATION**

This dual 2-input positive-OR gate is designed for 1.65-V to 5.5-V V<sub>CC</sub> operation.

The SN74LVC2G32 performs the Boolean function Y = A + B or  $Y = \overline{\overline{A} \bullet \overline{B}}$  in positive logic.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(2)</sup>	
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC2G32YZPR	CG_	
–40°C to 85°C	SSOP – DCT	Reel of 3000	SN74LVC2G32DCTR	C32	
	VSSOP – DCU	Reel of 3000	SN74LVC2G32DCUR	000	
	V3SOF - DC0	Reel of 250	SN74LVC2G32DCUT	- C32_	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. (2) DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

# SN74LVC2G32 **DUAL 2-INPUT POSITIVE-OR GATE**

SCES201L-APRIL 1999-REVISED FEBRUARY 2007



### **DESCRIPTION/ORDERING INFORMATION**

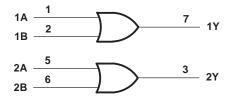
NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### **FUNCTION TABLE** (EACH GATE)

INP	INPUTS					
Α	В	Y				
Н	Х	Н				
Х	Н	н				
L	L	L				

#### LOGIC DIAGRAM (POSITIVE LOGIC)



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Voltage range applied to any output in th	ne high-impedance or power-off state <sup>(2)</sup>	-0.5	6.5	V
Vo	Voltage range applied to any output in th	ne high or low state <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through $V_{CC}$ or GND			±100	mA
		DCT package		220	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCU package		227	°C/W
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed. (2)(3) The value of V<sub>CC</sub> is provided in the recommended operating conditions table.

# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V	Supply voltogo	Operating	1.65	5.5	V
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		v
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65  imes V_{CC}$		
	l lieb level innut velteren	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		Ň
VIH	High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		V
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	$0.7  imes V_{CC}$		
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V		$V_{CC}$ = 2.3 V to 2.7 V		0.7	V
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		0.8	v
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		$0.3  imes V_{CC}$	
VI	Input voltage	· · ·	0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-4	
		V <sub>CC</sub> = 2.3 V		-8	
I <sub>OH</sub>	High-level output current	<u> </u>		-16	mA
	DH High-level output current	$V_{CC} = 3 V$		-24	
		V <sub>CC</sub> = 4.5 V	1.7 2 0.7 × V <sub>CC</sub> 0	-32	
		V <sub>CC</sub> = 1.65 V		4	
	Low-level input voltage      Input voltage      Output voltage      Output voltage      High-level output current      Low-level output current      Low-level output current      Δv    Input transition rise or fall rate	V <sub>CC</sub> = 2.3 V		8	
I <sub>OL</sub>	Low-level output current	<u> </u>		16	mA
		$V_{CC} = 3 V$		24	
		V <sub>CC</sub> = 4.5 V		32	
		$V_{CC}$ = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC}$ = 5 V ± 0.5 V	5		
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup>	MAX	UNIT		
	I <sub>OH</sub> = -100 μA	1.65 V to 5.5 V	V <sub>CC</sub> – 0.1				
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2				
N/	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9	V			
V <sub>OH</sub>	$I_{OH} = -16 \text{ mA}$	2.14	2.4		v		
	$I_{OH} = -24 \text{ mA}$	- 3 V	2.3				
	I <sub>OH</sub> = -32 mA	4.5 V	3.8				
	I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V		0.1			
	I <sub>OL</sub> = 4 mA	1.65 V		0.45	.45		
N/	I <sub>OL</sub> = 8 mA	2.3 V		0.3	V		
V <sub>OL</sub>	I <sub>OL</sub> = 16 mA	2.14		0.4			
	$I_{OL} = 24 \text{ mA}$	3 V		0.55			
	I <sub>OL</sub> = 32 mA	4.5 V		0.55			
II A or B inputs	$V_{I} = 5.5 \text{ V or GND}$	0 to 5.5 V		±5	μΑ		
l <sub>off</sub>	$V_{I}$ or $V_{O} = 5.5 V$	0		±10	μA		
I <sub>CC</sub>	$V_{I} = 5.5 \text{ V or GND}, \qquad I_{O} = 0$	1.65 V to 5.5 V		10	μA		
Δl <sub>CC</sub>	One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 5.5 V		500	μA		
C <sub>i</sub>	$V_{I} = V_{CC}$ or GND	3.3 V	5		pF		

(1) All typical values are at V<sub>CC</sub> = 3.3 V,  $T_A = 25^{\circ}C$ .

### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

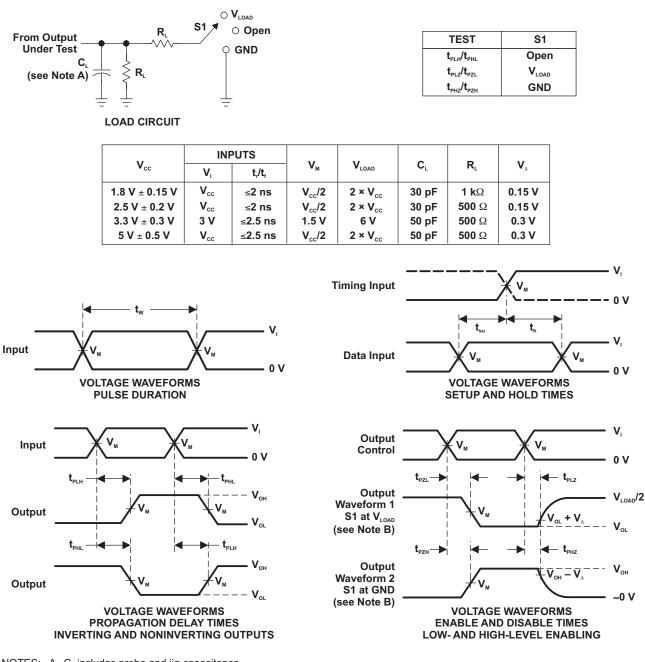
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		$V_{CC}$ = 2.5 V ± 0.2 V		$V_{CC}$ = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
	(INPUT)		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	2.4	8	1	4.4	1	3.8	1	3.2	ns

## **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

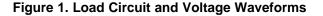
	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	$V_{CC} = 2.5 V$	V <sub>CC</sub> = 3.3 V	$V_{CC} = 5 V$	UNIT	
		1231 CONDITIONS	ТҮР	ТҮР	ТҮР	TYP		
C	C <sub>pd</sub> Power dissipation capacitance	f = 10 MHz	17	17	17	19	pF	

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_{\scriptscriptstyle L}$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{\mbox{\tiny PLZ}}$  and  $t_{\mbox{\tiny PHZ}}$  are the same as  $t_{\mbox{\tiny dis}}$
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{od}$ .
- H. All parameters and waveforms are not applicable to all devices.





11-Apr-2013

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN74LVC2G32DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32 Z	Samples
SN74LVC2G32DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32 Z	Samples
SN74LVC2G32DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32 Z	Samples
SN74LVC2G32DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32R CR	Samples
SN74LVC2G32DCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32R CR	Samples
SN74LVC2G32DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32R CR	Samples
SN74LVC2G32DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32R CR	Samples
SN74LVC2G32DCUTE4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32R CR	Samples
SN74LVC2G32DCUTG4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C32R CR	Samples
SN74LVC2G32YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(CG7 ~ CGN)	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



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# PACKAGE OPTION ADDENDUM

11-Apr-2013

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC2G32 :

• Automotive: SN74LVC2G32-Q1

Enhanced Product: SN74LVC2G32-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G32DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G32YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

26-Jan-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2G32DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74LVC2G32YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

# **MECHANICAL DATA**

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

#### DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCT (R-PDSO-G8) PLASTIC SMALL OUTLINE Example Board Layout Example Stencil Design (Note C,E) (Note D) - 6x0,65 - 6x0,65 8x0,25-8x1,55 3,40 3,40 Non Solder Mask Defined Pad Example Pad Geometry -0,30 (Note C) 1,60 Example -0,07 Non-solder Mask Opening All Around (Note E) 4212201/A 10/11

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



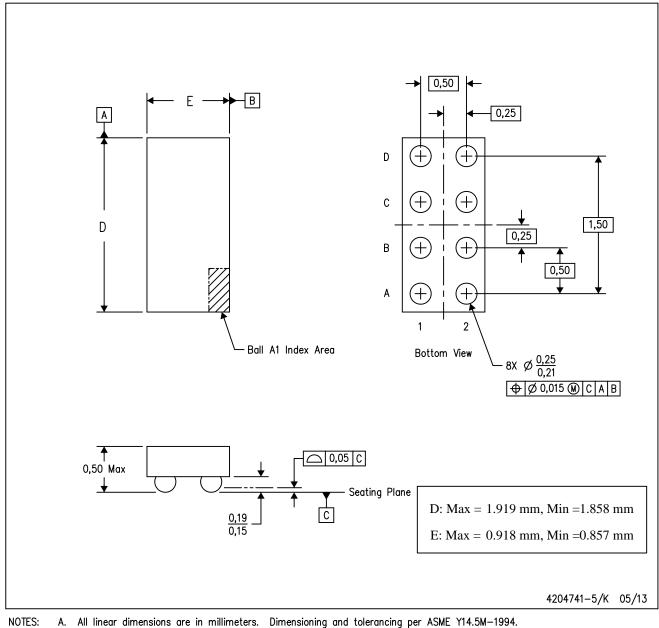


- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- A. All linear dimensions are in millimeters. Dimension B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

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